



IFW

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Docket No.: AMD-H0534

I hereby certify that this transmittal of the below described document is being deposited with the United States Postal Service in an envelope bearing First Class Postage and addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on the below date of deposit.

Date of Deposit:	10/15/04	Name of Person Making the Deposit:	Shannon Carmo	Signature of the Person Making the Deposit:	<i>Shannon Carmo</i>
------------------	----------	------------------------------------	---------------	---	----------------------

Inventor(s): Sheung Hee PARK, Richard M. FASTOW, Dong-Hyuk JU

Serial No.: 10/618,191 Group Art Unit: 2818

Filed: 07/10/2003 Examiner:

Title: FLASH MEMORY CELL HAVING REDUCED LEAKAGE CURRENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

TRANSMITTAL OF FORMAL DRAWINGS

In response to Drawing Informalities

attached please find:

(a) the formal drawings for this application

Number of Sheets 5

Each sheet of drawing indicates the identifying indicia suggested in § 1.84(c) on the reverse side of the drawing

(b) a copy of the NOTICE OF INFORMAL DRAWINGS

Please direct all correspondence concerning the above-identified application to the following address:

WAGNER, MURABITO & HAO LLP
Two North Market Street, Third Floor
San Jose, California 95113
(408) 938-9060
Customer Number: 45592

Respectfully submitted,

Date: October 15, 2004

By:


Eric J. Gash
Reg. No. 46,274